

# Technical Data Sheet 5mm Infrared LED, T-1 3/4

#### HIR8323/C16



#### **Features**

- High reliability
- High radiant intensity
- Peak wavelength  $\lambda$  p=850nm
- 2.54mm Lead spacing
- Low forward voltage
- Pb free
- The product itself will remain within RoHS compliant version.

#### **Descriptions**

- EVERLIGHT'S Infrared Emitting Diode(HIR8323/C16) is a high intensity diode, molded in a water clear plastic package.
- The device is spectrally matched with phototransistor, photodiode and infrared receiver module.

### **Applications**

- CCTV
- Infrared applied system

#### **Device Selection Guide**

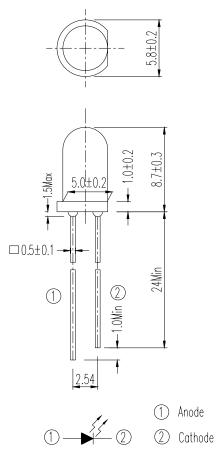
LED Part No.	Chip	Lens Color	
LED Part No.	Material		
HIR	GaAlAs	Water clear	

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### **Package Dimensions**



**Notes:** 1.All dimensions are in millimeters

2.Tolerances unless dimensions ±0.25mm

### **Absolute Maximum Ratings (Ta=25°C)**

Parameter	Symbol	Rating	Units
Continuous Forward Current	$I_{\mathrm{F}}$	100	mA
Peak Forward Current*1	$I_{FP}$	1.0	A
Reverse Voltage	$V_R$	5	V
Operating Temperature	$T_{\mathrm{opr}}$	-40 ~ +85	$^{\circ}\!\mathbb{C}$
Storage Temperature	$T_{stg}$	-40 ~ +85	$^{\circ}\!\mathbb{C}$
Soldering Temperature*2	$T_{sol}$	260	$^{\circ}\! \mathbb{C}$
Power Dissipation at(or below)	$P_d$	150	mW
25°C Free Air Temperature			

**Notes:** \*1: $I_{FP}$  Conditions--Pulse Width  $\leq$  100  $\mu$  s and Duty  $\leq$  1%.

\*2:Soldering time ≤ 5 seconds.

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# **Electro-Optical Characteristics** (Ta=25 $^{\circ}$ C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Units	
	${ m I_E}$	$I_F=20\text{mA}$	20	30	50	mW/sr	
Radiant Intensity		$I_F \!\!=\!\! 100mA$ Pulse Width $\leq \! 100\mus$ ,Duty $\leq \! 1\%$		120			
		$I_F=1A$ Pulse Width $\leq 100 \mu$ s ,Duty $\leq 1\%$ .		1200			
Peak Wavelength	λр	$I_F=20\text{mA}$		850		nm	
Spectral Bandwidth	Δλ	I <sub>F</sub> =20mA		40		nm	
Forward Voltage	$V_{\mathrm{F}}$	I <sub>F</sub> =20mA		1.45	1.65		
		$I_F \!\!=\! 100mA$ Pulse Width $\leq 100~\mu$ s ,Duty $\leq 1\%$		1.80	2.40	V	
		$I_F = 1A$ Pulse Width $\leq 100 \mu\text{s}$ ,Duty $\leq 1\%$ .		4.10	5.25		
Reverse Current	$I_R$	$V_R=5V$			10	$\mu$ A	
View Angle	2 \theta 1/2	I <sub>F</sub> =20mA		30		deg	

#### Rank

 $Condition : I_F \!\!=\!\! 20mA$ 

Unit: mW/sr

Bin Number	A	В
Min	20	25
Max	30	50

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### **Typical Electro-Optical Characteristics Curves**

Fig.1 Forward Current vs.

Ambient Temperature

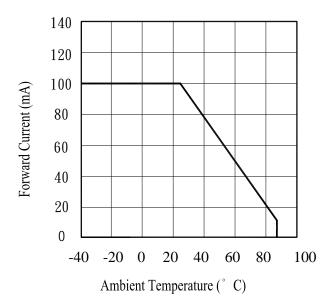


Fig.2 Spectral Distribution

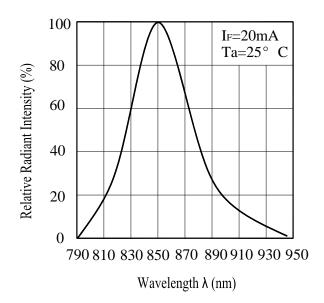


Fig.3 Peak Emission Wavelength
Ambient Temperature

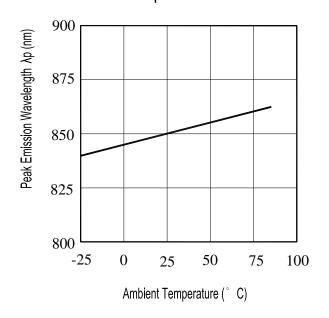
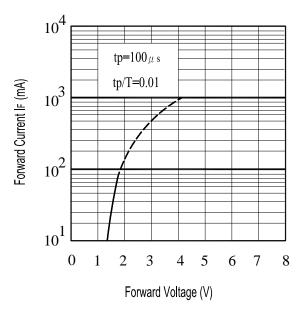


Fig.4 Forward Current vs. Forward Voltage



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# **Typical Electro-Optical Characteristics Curves**

Fig.5 Radiant Intensity vs.
Forward Current

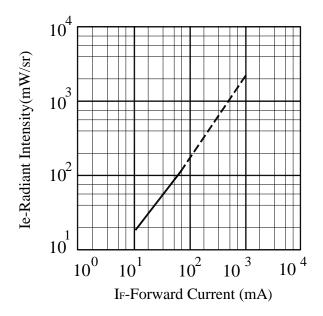


Fig.7 Radiant Intensity vs.

Ambient Temperature(°C)

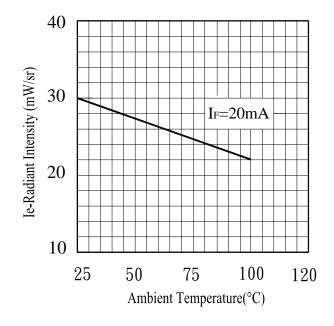


Fig.6 Relative Radiant Intensity vs.

Angular Displacement

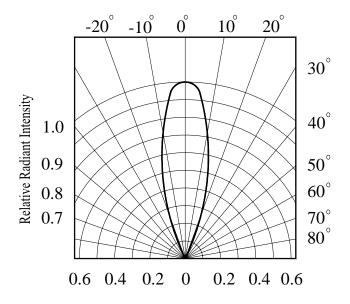
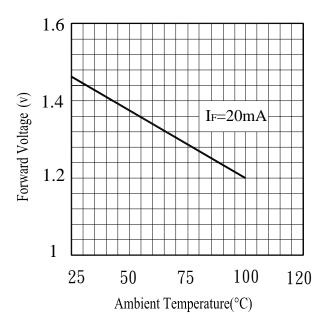


Fig.8 Forward Voltage vs.

Ambient Temperature(°C)



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### **Reliability Test Item And Condition**

The reliability of products shall be satisfied with items listed below.

Confidence level: 90%

LTPD: 10%

NO.	Item	Test Conditions	Test Hours/	Sample	Failure	Ac/Re
			Cycles	Sizes	Judgement	
					Criteria	
1	Solder Heat	TEMP. : 260°C±5°C	10secs	22pcs		0/1
2	Temperature Cycle	$H: +100^{\circ}C$ 15mins	300Cycles	22pcs	$I_R \ge U \times 2$	0/1
		5mins			$I_E \leq L \times 0.8$	
		L:-40°C 15mins			$V_F \ge U \times 1.2$	
3	Thermal Shock	H :+100°C <b>♦</b> 5mins	300Cycles	22pcs		0/1
		▼ 10secs			U: Upper	
		L:- $10^{\circ}$ C 5mins			Specification	
4	High Temperature	TEMP. : +100°C	1000hrs	22pcs	Limit	0/1
	Storage				L: Lower	
5	Low Temperature	TEMP. : -40°C	1000hrs	22pcs	Specification	0/1
	Storage				Limit	
6	DC Operating Life	I <sub>F</sub> =20mA	1000hrs	22pcs		0/1
7	High Temperature/	85°C /85% R.H	1000hrs	22pcs		0/1
	High Humidity					

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#### **Packing Quantity Specification**

1.500PCS/1Bag , 5Bags/1Box

2.10Boxes/1Carton

#### **Label Form Specification**



CPN: Customer's Production Numb

P/N: Production Number

QTY: Packing Quantity

**CAT: Ranks** 

**HUE: Peak Wavelength** 

REF: Reference

LOT No: Lot Number

MADE IN TAIWAN: Production Place

#### **Notes**

- 1. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
- 2. When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
- 3. These specification sheets include materials protected under copyright of EVERLIGHT corporation. Please don't reproduce or cause anyone to reproduce them without EVERLIGHT's consent.

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